# onsemi

### NDSH40120CDN

#### Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

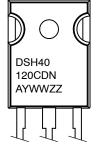
#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 166 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- This Device is Halide Free and RoHS Compliant with Exemption 7a, Pb–Free 2LI (on second level interconnection)

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits





A = As YWW = Da	becific Device Code ssembly Plant Code ate Code (Year & Week) t Code
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#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

### NDSH40120CDN

Unit V mJ А

> А А А А

W

W

°C

217

36

-55 to +175

ABSOLUTE MAXIMUM RATINGS (T <sub>J</sub> = 25°C unless otherwise noted) (per leg)					
Symbol	Parameter		Value		
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage		1200		
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)		166		
١ <sub>F</sub>	Continuous Rectified Forward Current @ T <sub>C</sub> < 149°C		20*/40**		
	Continuous Rectified Forward Current @ T <sub>C</sub> < 135°C		26*/52**		
I <sub>F, Max</sub>	Non-Repetitive Peak Forward Surge Current	tive Peak Forward Surge Current $T_{C} = 25^{\circ}C$ , 10 µs			
		T <sub>C</sub> = 150°C, 10 μs			
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current Half-Sine Pulse, $t_p = 8.3$ ms		123		
I <sub>F,RM</sub>	Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	49		

#### \_ . . .

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 $T_C = 25^{\circ}C$ 

 $T_C = 150^{\circ}C$ 

\*Per leg.

Ptot

TJ, TSTG

\*\* Per device.

1.  $E_{AS}$  of 166 mJ is based on starting  $T_J$  = 25°C, L = 0.5 mH, I<sub>AS</sub> = 25.8 A, V = 50 V.

Operating and Storage Temperature Range

#### THERMAL CHARACTERISTICS (per leg)

**Power Dissipation** 

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	0.69*/0.39**	°C/W
$R_{\theta JA}$	$R_{\theta JA}$ Thermal Resistance, Junction to Ambient, Max		°C/W

\*Per leg.

\*\* Per device.

#### ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise noted) (per leg)

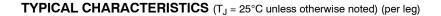
Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	$I_{\rm F} = 20 \text{ A}, \text{ T}_{\rm J} = 25^{\circ}\text{C}$	-	1.36	1.75	V
		$I_F = 20 \text{ A},  \text{T}_\text{J} = 125^\circ \text{C}$	-	1.60	-	
		$I_F = 20 \text{ A},  \text{T}_\text{J} = 175^\circ \text{C}$	-	1.81	-	
I <sub>R</sub>	Reverse Current	$V_{R} = 1200 \text{ V}, \text{ T}_{J} = 25^{\circ}\text{C}$	-	2.39	200	μΑ
		$V_{R}$ = 1200 V, $T_{J}$ = 125°C	-	6.91	200	
		$V_{R}$ = 1200 V, $T_{J}$ = 175°C	-	16.6	200	
Q <sub>C</sub>	Total Capacitive Charge	V = 800 V	-	95	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	1494	-	pF
		V <sub>R</sub> = 400 V, f = 100 kHz	-	80	-	1
		V <sub>R</sub> = 800 V, f = 100 kHz	-	60	-	1

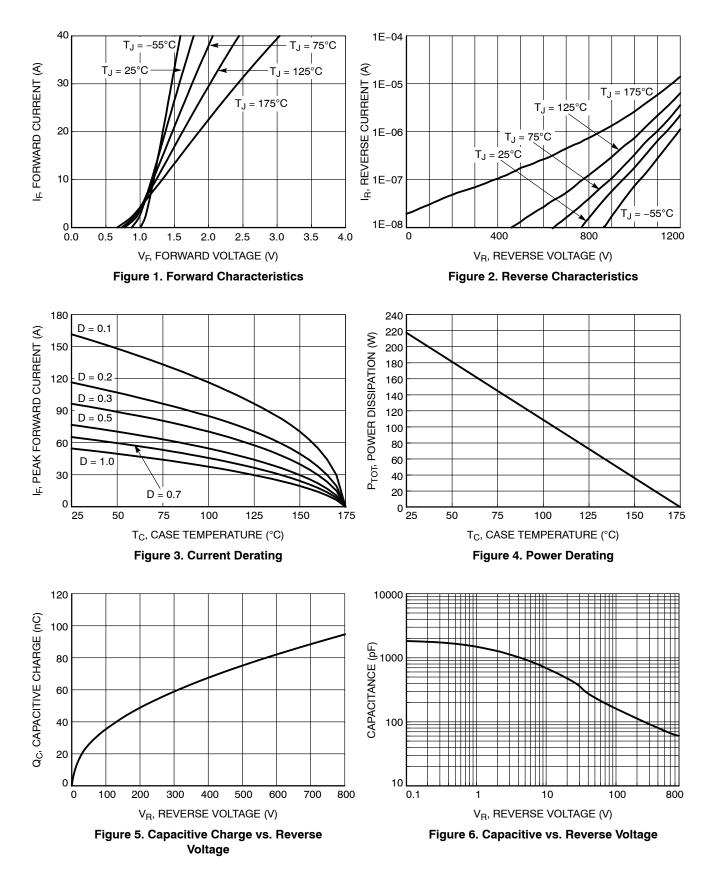
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Part Number	Top Marking	Package	Shipping
NDSH40120CDN	DSH40120CDN	TO-247-3LD (Pb-Free / Halogen Free)	30 Units / Tube

#### NDSH40120CDN





#### NDSH40120CDN

TYPICAL CHARACTERISTICS (T\_J =  $25^{\circ}$ C unless otherwise noted) (per leg)

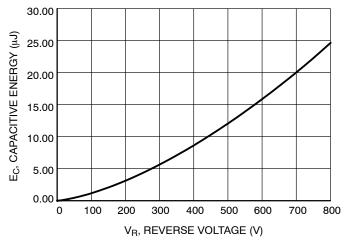


Figure 7. Capacitance Stored Energy

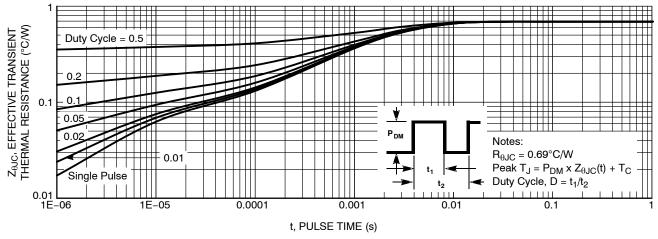


Figure 8. Junction-to-Case Transient Thermal Response Curve



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12.81

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E1

ØP1



D2

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